

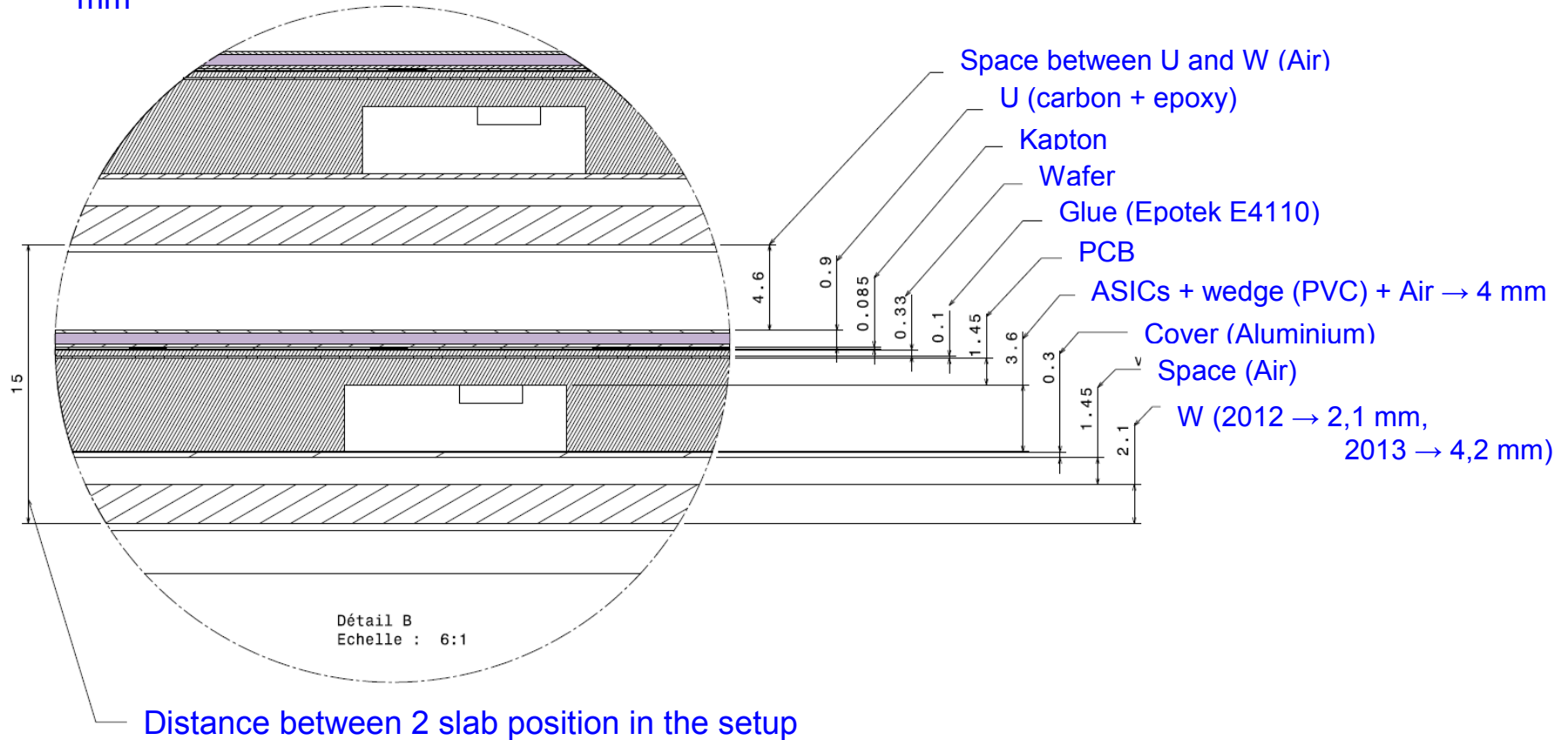
**Summary:**  
**Technological prototype simulation for DESY**  
**Test beam**

# Geometry

Thanks to Mickael and Rémi

Wafer: size = 88.49 mm  
Interpixel = 0,05 mm

All the values in mm



# Materials

Information from previous CALICE prototypes in Mokka, other experiments, manufacturers...

→ better to measure density and composition (if possible)

n → number of atoms  
f → mass fraction

W - Tungsten -  $d=19.3 \text{ g/cm}^3$

Kapton -  $d=1.42 \text{ g/cm}^3$

- + Carbon;  $f=0.691133$
- + Hydrogen;  $f=0.026362$
- + Oxygen;  $f=0.209235$
- + Nitrogen ;  $f=0.073270$

U -  $d=1.6 \text{ g/cm}^3$

- + Carbon;  $f=0.8466$
- + Hydrogen;  $f=0.0426$
- + Oxygen;  $f=0.0967$
- + Nitrogen ;  $f=0.0141$

Epotek

→ I considered homogeneous layer of Epotek4110 with reduced density to take into account space between glue dots.  $d=1.5 \text{ g/cm}^3$

ASICs (packaging)+ wedge (PVC) + Air

→ I considered homogeneous layer of PVC with reduced density to take into account empty regions (ASICs packaging is assimilated to PVC).  $d=0.9 \text{ g/cm}^3$

Wafer - Silicon -  $d=2.33 \text{ g/cm}^3$

Cover - Aluminium -  $d=2.7 \text{ g/cm}^3$

PCB -  $d=3. \text{ g/cm}^3$

- + Copper ;  $f=0.4276$
- + g10 ;  $f=0.5724$

Epotek4110 -  $d=2.57 \text{ g/cm}^3$

- + Carbon;  $f=0.431$
- + Hydrogen;  $f=0.046$
- + Oxygen;  $f=0.125$
- + Nitrogen ;  $f=0.014$
- + Silver ;  $f=0.385$

Epoxy -  $d=1.3 \text{ g/cm}^3$

- + Carbon;  $n=15$
- + Hydrogen;  $n=44$
- + Oxygen;  $n=7$

PVC -  $d=1.4 \text{ g/cm}^3$

- + Hydrogen ;  $n=3$
- + Carbon ;  $n=2$
- + Chlorine ;  $n=1$

G10 -  $d=1.7 \text{ g/cm}^3$

- + Epoxy;  $f=0.147$
- + Quartz;  $f=0.773$
- + Chlorine;  $f=0.08$

Quartz -  $d=2.2 \text{ g/cm}^3$

- + Silicon ;  $n=1$
- + Oxygen ;  $n=2$

# Energy measurement in simulation - Digitization

- Total energy deposited in one pixel (**step 1**)
- Geometrical cuts (inter-pixel gap)
- Electron-hole pair production fluctuation
- Electron-hole transport diffusion (**step 4**)
- Scaling using the landau MPV (keV  $\rightarrow$  ADC)
  - + Add PA noise (sigma from 2 to 4 ADC)
    - Apply trigger threshold (1 threshold per channel )
- Add SS noise (sigma = 1.4 ADC)
- Add pedestal (+ 300 ADC)
- Remove channels with switched off PA
  - ASIC data structure in simulation: 1 chip, 1 column, 324 channels

## Physics list:

EM option 3 (Standard G4 )

e, gamma production cuts = 10  $\mu$ m

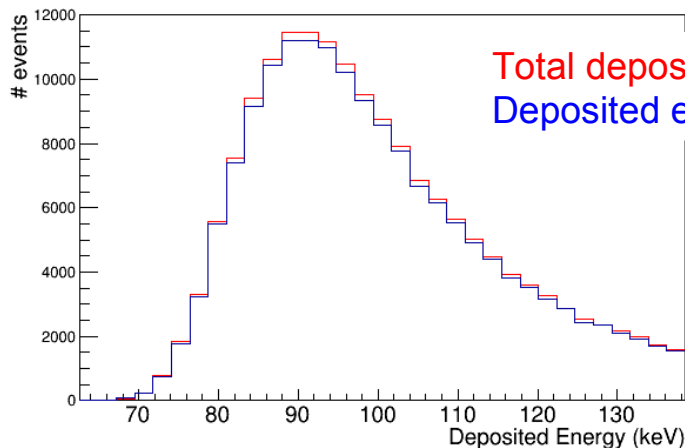
Cross section tables: 0,1 keV  $\rightarrow$  100 GeV (2000 bins)

Max step size in wafers = 5  $\mu$ m

$C_f = 1,2$  pF

$\rightarrow$  modify scaling factor and noise for other gains

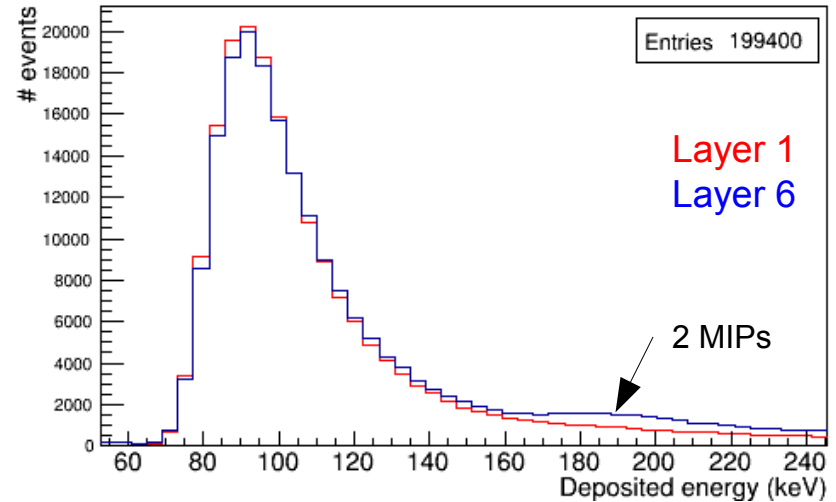
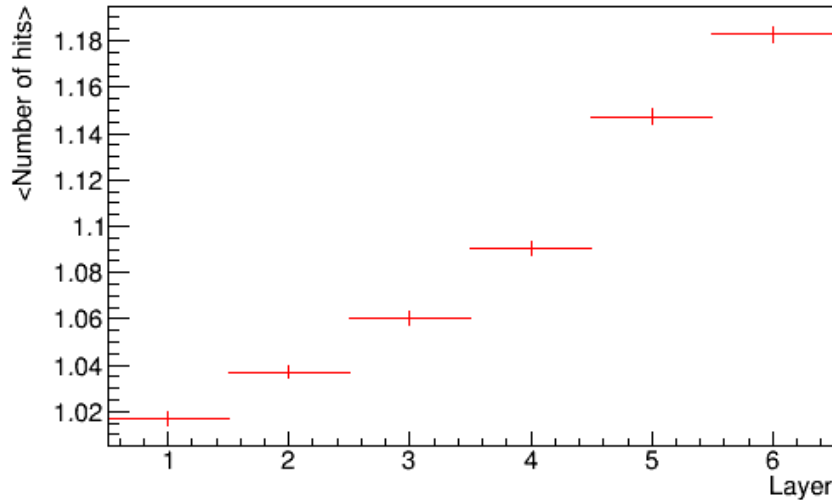
Not included: dispersion of channel response



Small effect of the geometrical cuts and electron-hole simulation  $\rightarrow$  Negligible?

# Effects of secondary particle production

Without trigger threshold cut



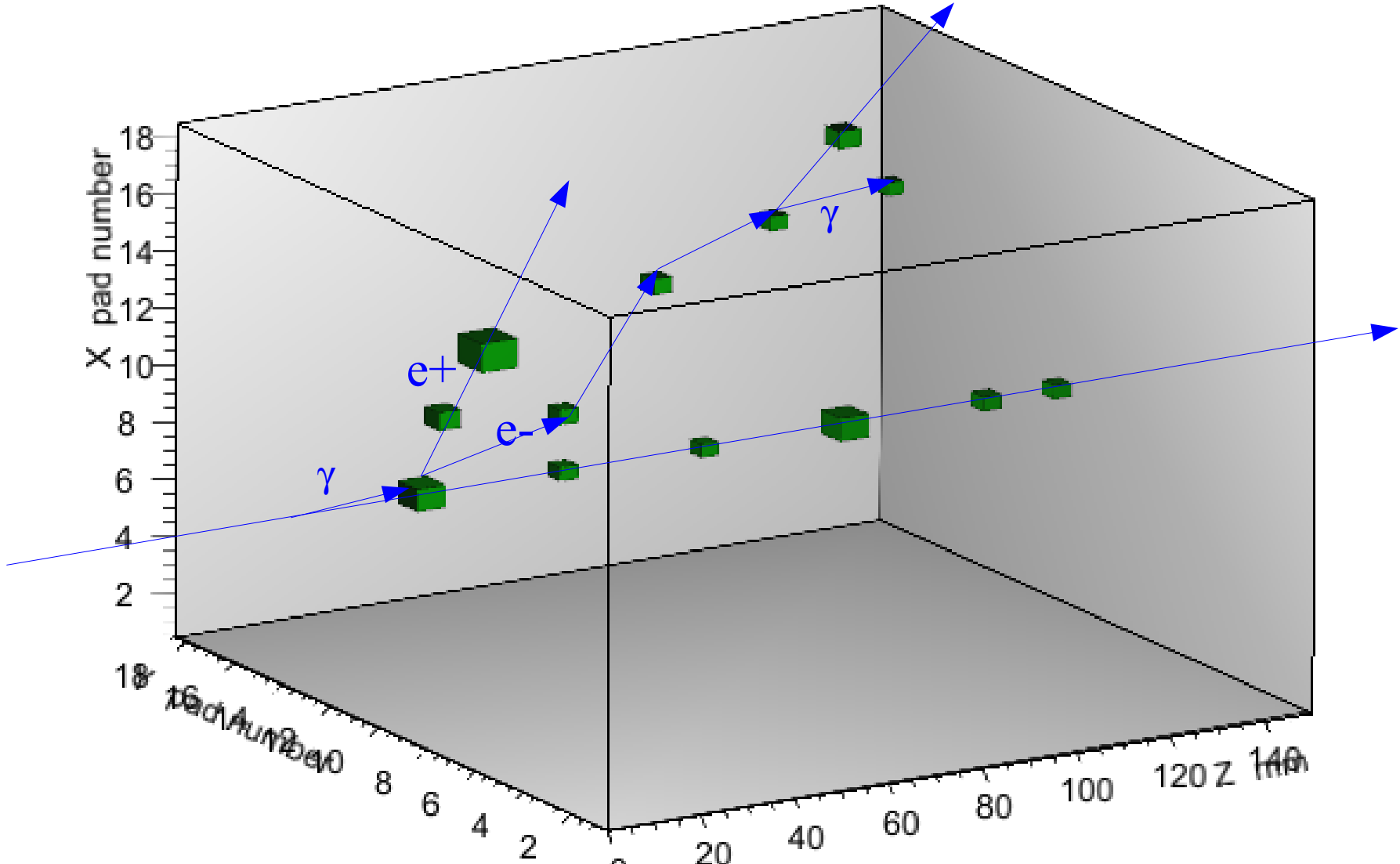
## DESY:

- electron beam
- E from 1 GeV to 5 GeV

Not negligible probability to produce secondary particles → Mean number of particles increases as a function of the layer number:

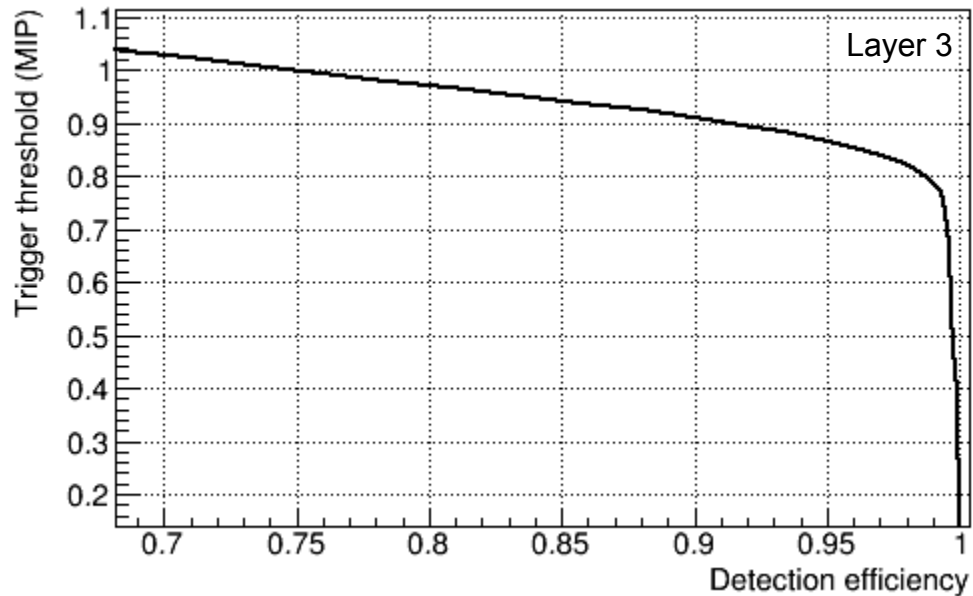
- Mean number of hits per event increases as a function of the layer number (effect on MIP detection efficiency calculation?)
- Energy spectrum is modified as a function of the layer number (effect on MIP energy calibration?)

# Secondary particles

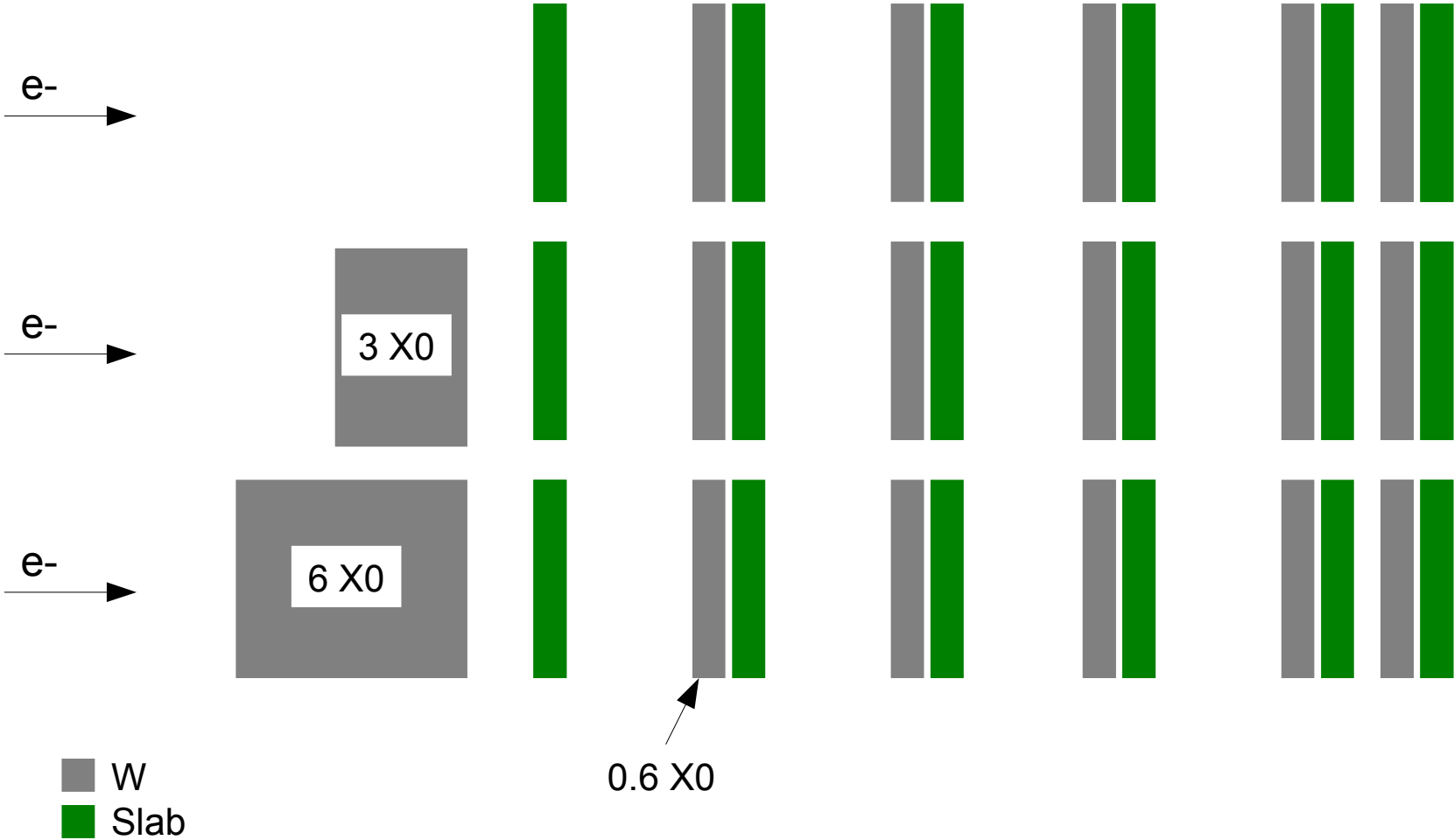


# Trigger threshold

Only the effect of the trigger threshold is studied : with a trigger threshold @0, the detection efficiency is 100% (geometrical effects ==> inefficiency < 2% → not taken into account)



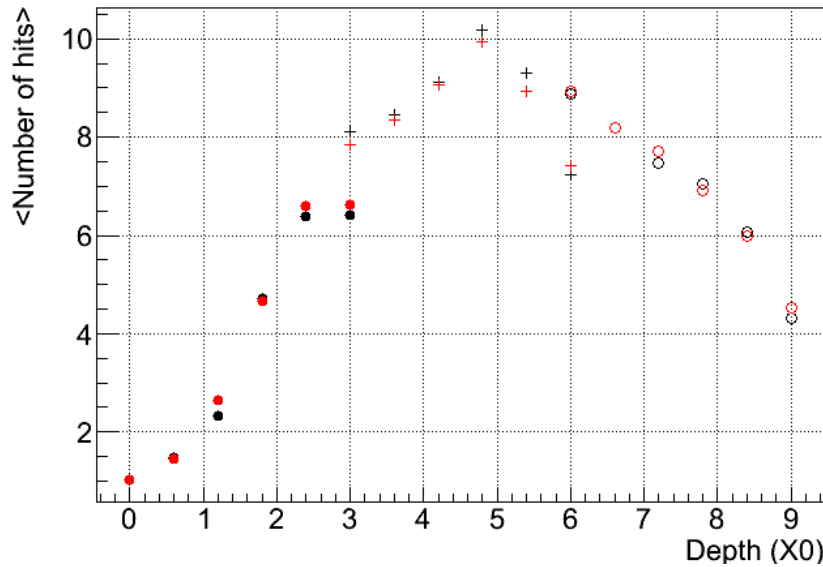
# Application to showers (summer 2012)



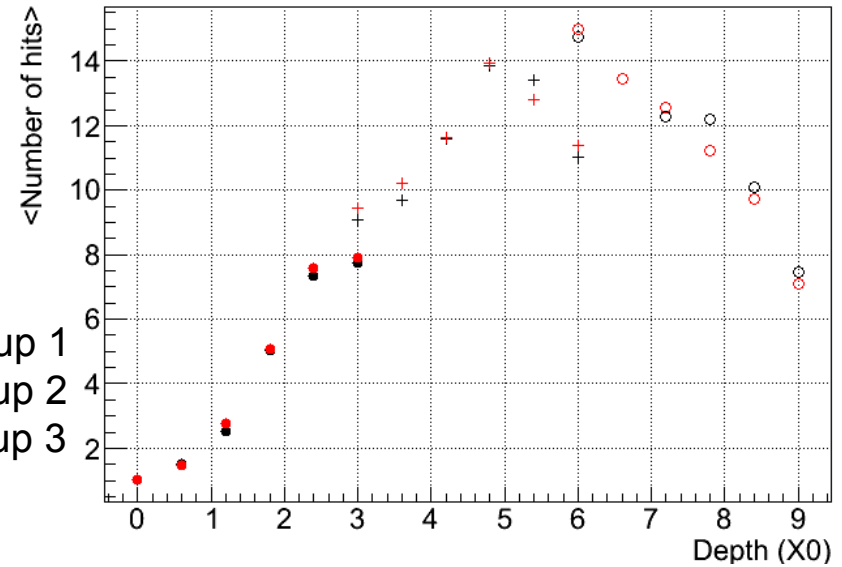


# Application to showers (summer 2012)

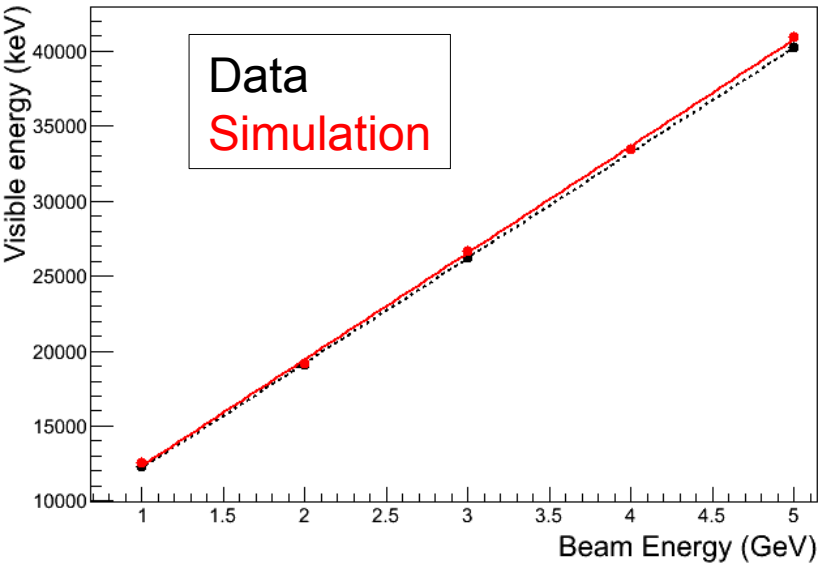
3 GeV



5 GeV



- Setup 1
- + Setup 2
- o Setup 3



Improvements of the simulation to be applied to summer 2013 TB to improve the results showed at the last CALICE meeting.